

CUSTOMER	:	
MODEL	:	MOG-128GB11D-S Series
DESCRIPTION	:	LCD MODULE

CUSTOMER APPROVAL

	CHECKED	CHECKED	APPROVAL
APPROVAL			
REMARK			

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1. General Specification

(1) Mechanical Dimension

Item	Standard Value		
Number of dots	128×64	dots	
Module dimension (L*W*H)	75.0 x 52.7 x 8.4	mm	
View area	60.0(W)×32.6(H)	mm	
Active area	56.02(W)×27.5(H)	mm	
Dot size	0.41(W)×0.41(H)	mm	
Dot pitch	0.43(W)×0.43(H)	mm	

(2) Controller IC: KS107 / KS108

(3) Temperature Range

	Normal	Wide
Operating	0 ~+50°C	-20 ~ +70°C
Storage	-10 ~ +60°C	-30 ~ +80°C

2. Absolute Maximum Ratings

Item	Symbol	Min	Тур	Max	Unit
Operating Temperature	T _{OP}	-20	—	+70	°C
Storage Temperature	T _{ST}	-30	—	+80	°C
Input Voltage	VI	0	—	V _{CC}	V
Supply Voltage For Logic	V _{CC}	0	—	67	V
Supply Voltage For LCD	V_{CC} - V_{LCD}	0	—	16.7	V
Supply Voltage For LCD	V _{OUT}	—	—	-10	V

03 of 18

3. Electrical Characteristics

Item	Symbol	Condition	Min.	Тур.	Max.	Unit
Supply Voltage For Logic	V_{DD} - V_{SS}	—	4.5	5.0	5.5	V
		Ta=-20°C	_	9.8	—	V
Supply Voltage For LCD	V_{DD} - V_0	Ta=25℃	_	8.5	_	V
		Ta=+70°C	—	7.5	_	V
Input High Vol	V _{IH}	—	$0.7 V_{DD}$	—	V _{DD}	V
Input Low Vol	V _{IL}	_	0	—	$0.3V_{DD}$	V
Output High Vol	V _{OH}	—	2.4	—	—	V
Output Low Vol.	V _{OL}	_	—	—	0.4	V
Supply Current	I _{DD}	_	—	6.0	_	mA

4. Optical Characteristics

a. STN

Item	Symbol	Condition	Min.	Тур.	Max.	Unit
	$(V) \theta$	$CR \ge 2$	10		45	deg
View Angle	(H) φ	$CR \ge 2$	-30		30	deg
Contrast Ratio	CR	—		3		_
Response Time	T rise	_		100	150	ms
25°C	T fall	_		150	200	ms

b. FSTN

Item	Symbol	Condition	Min.	Тур.	Max.	Unit
View Angle	$(V)\theta$	CR≧3	10		60	deg
View Aligie	(H) φ	$CR \ge 3$	-45		45	deg
Contrast Ratio	CR	_		5		
Response Time	T rise	—		100	150	ms
25°C	T fall	_		150	200	ms



4.1 Definitions



05 of 18

5. Interface Pin Function

Pin No.	Symbol	Level	Description
1	Vdd	5.0V	Supply voltage for logic (option +3V)
2	GND	0V	Ground
3	Vo	(Variable)	Operating voltage for LCD
4	DB0	H/L	Data bus line
5	DB1	H/L	Data bus line
6	DB2	H/L	Data bus line
7	DB3	H/L	Data bus line
8	DB4	H/L	Data bus line
9	DB5	H/L	Data bus line
10	DB6	H/L	Data bus line
11	DB7	H/L	Data bus line
12	/CS1	L	Chip Select for IC1
13	/CS2	L	Chip Select for IC2
14	/RST	L	Reset signal
15	R/W	H/L	H=Read mode , L=Write mode
16	D/I	H/L	H=Data register , L=Instruction register
17	Е	H/L	Enable signal
18	Vee		Negative Voltage output –4.8V
19	А	_	Power supply for B/L (+)
20	K	_	Power supply for B/L (GND)

6. Timing Characteristics

MPU Interface

Characteristic	Symbol	Min	Typ	Max	Unit
E cycle	tcyc	1000	_	_	ns
E high level width	twhE	450	_	_	ns
E low level width	twlE	450	_	_	ns
E rise time	tr	_	_	25	ns
E tall time	tf	_	_	25	ns
Address set-up time	tas	140	_	_	ns
Address hold time	tah	10	_	_	ns
Data set-up time	tdsw	200	_	_	ns
Data delay time	tddr	_	_	320	ns
Data hold time (write)	tdhw	10	_	_	ns
Data hold time (read)	tdhr	20	_	_	ns



MPU Write Timing





MPU Read Timing



7. Power Supply for LCD Module and LCD Operating Voltage a Adjustment

*LCM operating on " DC 5V " input with built-in negative voltage



*(Option) LCM operating on " DC 5V " input with external negative voltage



*(Option) LCM operating on " DC 3V " input with external negative voltage





*(Option) LCM operating on " DC 3V " input with built-in negative voltage



8. Backlight Information

8.1 Specification

LED edge / yellow-green

Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Supply Current	ILED		70	100	mA	V=4.0V
Supply Voltage	V		4.0	4.2	V	_
Reverse Voltage	VR	_	_	8	V	_
Luminous Intensity	IV	18	20	_	cd/m ²	ILED=70mA
Wave Length	λp	_	574	_	nm	ILED=70mA
Life Time		_	70000	_	Hr.	$V \leq 4.2 V$
Color	Yellow-green					

(2) LED white / blue

Parameter	Symbol	Min	Тур	Max	Unit	Test Condition	
Supply Current	ILED		30	45	mA	V=3.2V	
Supply Voltage	V		3.2	3.3	V	_	
Reverse Voltage	VR	_	_	8	V	_	
Luminous Intensity	IV	30	40	_	cd/m ²	ILED=30mA	
Wave Length	λp	_		_	nm	ILED=30mA	
Life Time		_	20000	_	Hr.	V≦3.3V	
Color	White						



8.2 Backlight driving methods

a.

a-1 LED edge/yellow-green B/L drive from pin19 (LED+) pin20 (LED-)



a-2 LED white(blue) B/L drive from pin19 (LED+) pin20 (LED-)



b.*(Option) LED B/L drive from pin1 (Vdd) pin2 (Vss)



(1)Jump 1,2 Short

(2)Current Resistor required on RL

(3) Jump 19,20 open

(4) To be sure of enough current supply for both VDD + LED B/L

c. E/L B/L driven from A.K directly





9. Display Control Instruction

The display control instructions control the internal state of the KS0108B. Instruction is received from MPU to KS0108B for the display control. The following table shows various instructions.

Instruction	D/I	R/W	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0	Function
Display ON/OFF	0	0	0	0	1	1	1	1	1	0/1	Controls the display on or off. Internal status and display RAM data are not affected. 0:OFF, 1:ON
Set Address	0	0	0	1		Y a	ddres	ss (0~	63)		Sets the Y address in the Y address counter.
Set Page (X address)	0	0	1	0	1	1	1	Pag	ge (0	~7)	Sets the X address at the X address register.
Display Start Line	0	0	1	1	D	Displa	y star	t line	(0~63	3)	Indicates the display data RAM displayed at the top of the screen.
Status Read	0	1	B U S Y	0	ON/ OFF	R E S E T	0	0	0	0	Read status. BUSY 0:Ready 1:In operation ON/OFF 0:Display ON 1:Display OFF RESET 0:Normal 1:Reset
Write Display Data	1	0			D	Displa	y Dat	a			Writes data (DB0:7)into display data RAM. After writing instruction, Y address is increased by 1 automatically.
Read Display Data	1	1			Display Data				Reads data (DB0:7) from display data RAM to the data bus.		

9.1 Detailed Explanation

Display On/Off

R/W	D/I	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0
0	0	0	0	1	1	1	1	1	D

The display data appears when D is and disappears when D is 0. Though the data is not on the screen with D = 0, it remains in the display data RAM. Therefore, you can make it appear by changing D = 0 into D = 1.

Display Start Line

R/W	D/I	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0
0	0	1	1	A	А	А	A	А	А

Z address AAAAAA (binary) of the display data RAM is set in the display start line register and displayed at the top of the screen. Figure 2. shows examples of display (1/64 duty cycle) when the start line = 0-3. When the display duty cycle is 1/64 or more (ex. 1/32, 1/24 etc.), the data of total line number of LCD screen, from the line specified by display start line instruction, is displayed.

Set Page (X Address)

R/W	D/I	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0
0	0	1	0	1	1	1	А	А	А

X address AAA (binary) of the display data RAM is set in the X address register. After that, writing

or reading to or from MPU is executed in this specified page until the next page is set. See Figure 1.

Set Y Address

R/W	D/I	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0
0	0	0	1	А	А	А	А	А	А

Y address AAAAAA (binary) of the display data RAM is set in the Y address counter. After that, Y address counter is increased by 1 every time the data is written or read to or from MPU.

Status Read

R/W	D/I	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0
0	0	Busy	0	On/Off	RESET	0	0	0	0

•Busy

When busy is 1, the LSI is executing internal operations. No instruction are accepted while busy is 1, so you should make sure that busy is 0 before writing the next instruction.

•ON/OFF

Shows the liquid crystal display condition: on condition or off condition.

When on/off is 1, the display is in off condition.

When on/off is 0, the display is in on condition.

•RESET

RESET = 1 shows that the system system is being initialized. In this condition, no instructions except status read can be accepted.

RESET = 0 shows that initializing has system is in the usual operation condition.

Write Display Data

R/W	D/I	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0
0	0	D	D	D	D	D	D	D	D

Writes 8-bit data DDDDDDDD (binary) into the display data RAM. The Y address is increased by 1 automatically.

Read Display Data

R/W	D/I	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0
0	0	D	D	D	D	1	D	D	D

Reads out 8-bit data DDDDDDD (binary) from the display data RAM. Then Y address

is increased by 1 automatically.

14 of 18

One dummy read is necessary right after the address setting. For details, refer to the explanation of output register in "Function of Each Block".



Figure 1.

MOG-128GB11D-S Series

15 of 18







Start line = 1



Start line = 3



Start line = 4





10. Quality Assurance

Screen Cosmetic Criteria

No.	Defect	Judgement Criterion	Partition
		A) Clear	
		Size:d mmAcceptable Qty in active area	
		d ≤ 0.1 Disregard	
		$0.1 \le d \le 0.2$ 6	
	Spots	$0.2 < d \le 0.3$ 2	
		0.3 <d 0<="" td=""><td></td></d>	
1		Note:Including pin holes and defective dots which	
1	Spots	must be within one pixel size.	Minor
		B) Unclear	
		Size:d mm Acceptable Qty in active area	
		$d \leq 0.2$ Disregard	
		$0.2 < d \le 0.5$ 6	
		$0.5 < d \le 0.7$ 2	
		0.7 <d 0<="" td=""><td></td></d>	
		Size:d mm Acceptable Qty in active area	
	D-111-	$d \leq 0.3$ Disregard	
2	Bubbles in	$0.3 < d \le 1.0$ 3	Minor
	Polarizer	$1.0 < d \le 1.5$ 1	
		1.5 <d 0<="" td=""><td></td></d>	
		In accordance with spots cosmetic criteria. When	
3	Scratch	the light reflects on the panel surface, the scratches	Minor
		are not to be remarkable.	
4	Allowable Density	Above defects should be separated more than	Minor
4	Allowable Delisity	30mm each other.	WIIIOI
		Not to be noticeable coloration in the viewing area	
5	Coloration	of the LCD panels.	Minor
5		Back-light type should be judged with back-light	10111101
		on state only.	

11. Reliability

Content of Reliability Test

		Environmental Tes	st	
No.	Test Item	Content of Test	Test Condition	Applicable Standard
1	High Temperature storage	Endurance test applying the high storage temperature for a long time.	80°C 200hrs	
2	Low Temperature storage	Endurance test applying the high storage temperature for a long time.	-30°C 200hrs	
3	High Temperature Operation	Endurance test applying the electric stress (Voltage & Current) and the thermal stress to the element for a long time.	70°C 200hrs	
4	Low Temperature Operation	Endurance test applying the electric stress under low temperature for a long time.	-20°C 200hrs	
5	High Temperature/ Humidity Storage	Endurance test applying the high temperature and high humidity storage for a long time.	60℃,90%RH 96hrs	
6	High Temperature/ Humidity Operation	Endurance test applying the electric stress (Voltage & Current) and temperature / humidity stress to the element for a long time.	40℃,90%RH 96hrs	
7	Temperature Cycle	Endurance test applying the low and high temperature cycle. -30°C 25°C 80°C 30min 5min 30min	-30°C/80°C 10 cycles	
		l cycle Mechanical Test		
8	Vibration test	Endurance test applying the vibration during transportation and using.	10~22Hz→1.5mmp-p 22~500Hz→1.5G Total 0.5hrs	
9	Shock test	Constructional and mechanical endurance test applying the shock during transportation.	50G Half sign wave 11 msedc 3 times of each direction	
10	Atmospheric pressure test	Endurance test applying the atmospheric pressure during transportation by air.	115mbar 40hrs	
	I	Others		
11	Static electricity test	Endurance test applying the electric stress to the terminal.	VS=800V,RS=1.5kΩ CS=100pF 1 time	

***Supply voltage for logic system=5V. Supply vo



12.Outline Dimension

